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Preparation, Properties and Crystal Structure of Barium Vanadium Sulfide, BaVS₃*

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Barium vanadium sulfide, BaVS₃, has been prepared and single crystals have been grown from a barium chloride flux. The crystal structure of BaVS₃ at room temperature has been determined by single-crystal analysis and the space group is *P6₃/mmc* with two formula units per unit cell. The hexagonal cell dimensions are $a = 6.724 \pm 0.005$ Å and $c = 5.610 \pm 0.005$ Å. The calculated density is 4.30 g.cm⁻³ and the observed density is 4.22 g.cm⁻³. The structure has been refined by least-squares techniques to a final *R* value on *F* of 7.5% for 192 independent reflections above background. The structure is based on hexagonal close-packed BaS₃ layers with the vanadium cations occupying one quarter of the octahedral voids between these layers. These are all the voids that are bounded exclusively by anions. The vanadium cations form chains parallel to the *c* axis with a V-V distance of 2.805 ± 0.002 Å. Low temperature powder X-ray studies indicate that a crystallographic distortion begins to occur near 185°K and this distortion gradually increases as the temperature is decreased. At liquid nitrogen temperature the distortion is considerable, but its exact nature is unknown. A plot of resistivity as a function of temperature indicates a change in the slope at approximately 130°K. This change is associated with a transition from the metallic to the semiconducting state. The electrical properties of BaVS₃, in the metallic state, are discussed in terms of direct interactions between the vanadium cations.

Introduction

Katz & Ward (1964) have recently described the structures of a number of mixed metal oxides in terms of the stacking sequence of essentially close-packed metal-oxygen layers. The concept of structure in terms of stacking sequences permits the correlation of a large number of structure types. In addition, it is possible to utilize these ideas in order to predict the existence of new compounds.

Compounds of the type ABX₃ where A is a large cation, B a small cation, and X is an anion, can be described as an essentially close-packed array of A and X ions, provided A and X are approximately the same size. In such an array, one quarter of the octahedral voids are bounded exclusively by the anions; these are the octahedra occupied by the B cations. The well known perovskite-type structure may be described in terms of cubic close-packing of the AX₃ layers. If the stacking sequence of the close-packed layers is hexa-

gonal, then a different structure-type results. In addition, other structure-types can be described in terms of different sequences of hexagonal and cubic layers. The structure of compounds with a common packing sequence has usually been classified according to the crystal structures of minerals or specific compounds, e.g. perovskite, spinel, nickel arsenide, etc. This may at times lead to confusion because many such compounds often show marked differences in their crystallographic properties; a common packing sequence does not necessarily imply a common crystal structure. In this study it is preferred to designate the compounds according to the packing sequence rather than by association with the structure of a particular class of minerals or compounds.

In ABX₃ compounds with a cubic close-packed arrangement of ions, the octahedra occupied by B cations share corners; in the hexagonal close-packed structure these octahedra share faces and form continuous chains parallel to the *c* axis of the crystal. The ternary transition metal sulfides and selenides BaTiS₃ (Hahn & Mutschke, 1956; Clearfield, 1963; Aslanov & Kovba, 1964), BaTiSe₃ (Aslanov, 1964), SrTiS₃ (Hahn &

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Mutschke, 1956), BaTaS₃ (Aslanov & Kovba, 1964), BaTaSe₃ (Aslanov, 1964), BaZrSe₃ (Aslanov, 1964), appear to crystallize with the hexagonal close-packed type structure. The room temperature form of BaVS₃, which has not previously been reported, can be classified with this group of compounds. This structure is also similar to that of CsNiCl₃ (Tishchenko, 1955), in which the nickel cations occupy one quarter of the octahedral voids between close-packed CsCl₃ layers. In addition BaNiO₃ (Lander, 1951) has been reported, on the basis of powder work, to have a similar structure. The stoichiometry of BaNiO₃, however, has been questioned (Gushee, Katz & Ward, 1957). In the room temperature form of BaVS₃ the vanadium cations, which occupy one quarter of the face shared octahedra, form continuous chains. If the V-V distance is sufficiently small, then there may be enough overlap of the transition metal *d*-orbitals to result in the formation of conduction bands. This has been observed for other ternary vanadium chalcogenides (Bouchard, Robinson & Wold, 1966). Since the *d*-orbitals of vanadium in the compound BaVS₃ contain only one electron, the conduction bands would only be partially filled and metallic conduction should result.

Previous studies of V³⁺ and V⁴⁺ oxides (Perrakis, 1927; Hoschek & Klemm, 1939; Rüdorff, Walter & Stadler, 1958; Morin, 1959; Warekois, 1960; Goodman, 1962; Goodenough, 1963; Feinleib & Paul, 1967) indicate that crystallographic transitions occur in these compounds which may result in a change from semi-conducting to metallic behavior. This transition results from the formation of covalent V-V bonds with the trapping of conduction electrons (Goodenough, 1965). It was therefore decided to investigate the electrical and crystallographic properties of BaVS₃ at low temperatures in order to ascertain the nature of the V-V bonding in this compound.

Experimental

Preparation

BaVS₃ was prepared by heating an intimately ground mixture of barium carbonate and vanadium pentoxide ('Specpure' Johnson, Matthey & Co., Ltd.) at 500°C for 12 hours and then at 900°C for 24 hours in a hydrogen sulfide atmosphere.

Crystal growth

Single crystals of BaVS₃ were grown using barium chloride as a flux. A mixture of the sulfide and flux was placed in an evacuated silica tube and then sealed inside a second silica tube. This procedure prevented any exposure of the melt to air, since the inner tube tended

to devitrify and crack. The double-tubed sample was heated to 1050°C and held at that temperature for 12–24 hours. The furnace was then programmed to cool from 1050°C to 800°C at 3°/hour and then to room temperature at 50°/hour. The melt was extracted with cold water, filtered and washed with acetone. The larger crystals were separated from the treated melt by passing the mixture through a series of standard sieves. The largest crystals grown by this technique were 0.5 to 3 mm long. They were gold-colored and grew primarily in the habit of first order hexagonal prisms {10 $\bar{1}$ 0}, although some crystals formed as small hexagonal platelets {0001}.

Analyses

Both the polycrystalline and single crystal forms of BaVS₃ were analyzed. Barium was determined by a standard gravimetric sulfate procedure after the sample was dissolved in hot 6*N* hydrochloric acid. Vanadium was determined volumetrically by titration with standardized ferrous ammonium sulfate solution. Sulfur in the polycrystalline sample was determined by oxidizing the sample in a stream of oxygen at 500°C and measuring the gain in weight of the sample. The products of the oxidation are barium sulfate and vanadium pentoxide, as verified by X-ray diffraction. The weight gain upon oxidation was related to the amount of sulfur initially present. The single crystals were analyzed for barium, vanadium and chlorine. The sulfur content was determined by difference. The amount of chloride present in the single crystals was determined

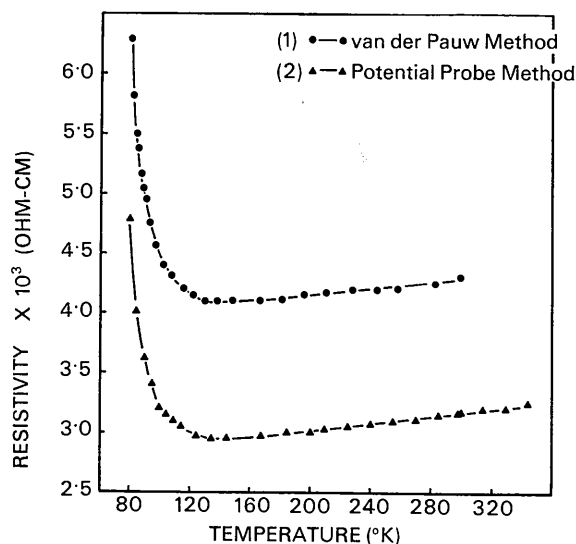


Fig. 1. Resistivity vs. temperature for BaVS₃.

Table 1. Analytical results

	% Ba		% V		% S		% Cl
	found	calc.	found	calc.	found	calc.	found
Polycrystalline sample	48.25	48.28	17.83	17.91	33.88	33.81	—
Single crystals	48.04	48.28	17.88	17.91	33.63	33.81	0.45

Table 3. *Positional and thermal parameters**†

	<i>x</i>	<i>y</i>	<i>z</i>	β_{11}	β_{22}	β_{33}
S	0.1656 (6)	0.3312 (6)	$\frac{1}{2}$	63 (9)	66 (9)	125 (12)
V	0	0	0	141 (10)	141 (10)	118 (17)
Ba	$\frac{1}{2}$	$\frac{2}{3}$	$\frac{1}{2}$	87 (4)	87 (4)	114 (7)

* The standard deviations are shown in parenthesis and refer to the last decimal position of the respective values.

† The temperature factor expression used was $\exp[-10^{-4}(h^2\beta_{11} + k^2\beta_{22} + l^2\beta_{33} + 2hk\beta_{12} + 2hl\beta_{13} + 2kl\beta_{23})]$. Constraints placed on the β_{ij} 's are: for sulfur $\beta_{11} = 2\beta_{12}$, $\beta_{23} = \beta_{13} = 0$, and for vanadium and barium $\beta_{11} = \beta_{22} = 2\beta_{12}$, $\beta_{23} = \beta_{13} = 0$.

given zero weight in the refinement. For the refinement procedure, one overall scale factor was used.

Three cycles of isotropic least-squares refinement led to the following *R* indices:

$$R = \frac{\sum ||F_o| - |F_c||}{\sum |F_o|} = 0.095,$$

$$wR = \left[\frac{\sum w(|F_o| - |F_c|)^2}{\sum w|F_o|^2} \right]^{1/2} = 0.107.$$

The refinement was continued in the centrosymmetric space group with three cycles of anisotropic calculations. The final values of *R* and *wR* for the observed data were 0.075 and 0.083 respectively. In addition, the final error of fit was 1.298. These results indicate a moderate decrease in *wR* that seems to justify the anisotropic refinement. The final positional and thermal parameters of this refinement are given in Table 3. Interatomic distances, bond angles and standard deviations were calculated by the use of the Busing, Martin & Levy (1964) ORFFE program and are shown in Table 4. The final structure amplitudes are given in Table 3.

Table 4. *Selected distances and bond angles**

Atoms	Distance (Å)	Atoms (central atom is vertex)	Angle (°)
S'—V'	2.385 (3)	S'—V'—S''	91.07 (15)
S'—Ba''	3.362 (3)	S'—V'—S ^{vi}	88.93 (8)
S''—Ba''	3.418 (3)	S'—V'—S ^{iv}	180.00 (8)
S'—S''	3.404 (2)	V'—Ba''—V''	39.73 (4)
V'—V''	2.805 (2)	S'—Ba''—V''	35.30 (3)
S'—S ^{vi}	3.340 (2)		
V'—Ba''	4.128 (3)		
Ba'—Ba''	4.790 (3)		

Root-mean-square radial thermal displacements of atoms (Å)

S	0.206
V	0.260
Ba	0.220

* Errors in cell parameters are included in the standard deviations.

The above results indicate that a reasonable refinement was obtained in the centrosymmetric *P6₃/mmc* space group. In the absence of any stereochemical evidence which would show that the choice is incorrect, the centrosymmetric group is assumed.

Low temperature X-ray study

Powder samples of BaVS₃ were mixed with colloidal and amyl acetate and spread on an aluminum-

backed Pyrex slide with a copper-constantan thermocouple mounted between the aluminum and pyrex. The samples were then examined using monochromatized (AMR-202 focusing monochromator) high intensity copper radiation [$\lambda(\text{Cu } K\alpha)1.5405 \text{ \AA}$] with a Norelco diffractometer. The radiation was detected with a Norelco scintillation counter. A temperature of approximately 77°K was reached by blowing liquid nitrogen directly on to the sample. To obtain temperatures between that of liquid nitrogen and room temperatures an apparatus similar to that described by Post, Schwartz, & Fankuchen (1951) was used.

Results and discussion

Analyses of the product obtained from various crystal growth experiments indicated that less than 0.5% chlorine from the flux was present in the samples. The small amount of chlorine present in the crystals should not affect the crystallographic results reported. However, since electrical properties are affected by impurity content, resistivity and Seebeck measurements were not made on the small crystals but on well-characterized sintered bars.

A representation of the room temperature structure of BaVS₃ is shown in Fig. 2 and indicates the parallel chains of vanadium cations. There are also columns of unoccupied octahedra, with barium cations at two of their opposite corners, which share edges with the vanadium occupied octahedra shown in the Figure. The

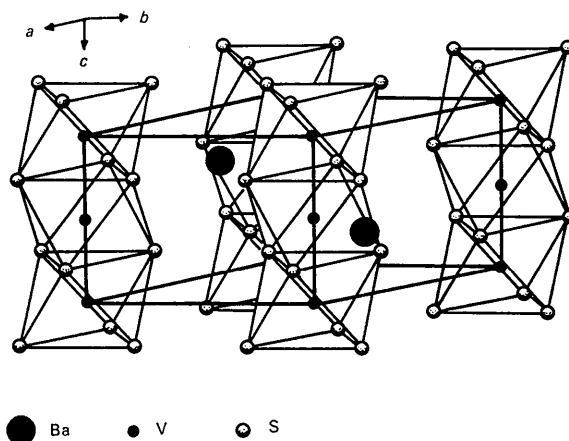


Fig. 2. Structure of BaVS₃ showing chains of face-sharing sulfur octahedra. The hexagonal unit cell is outlined with bold lines.

unoccupied octahedra are not shown for the sake of simplicity. Fig. 3 shows the packing sequence of the nearly close-packed BaS_3 layers perpendicular to the c axis; the vanadium cations occupy one quarter of the octahedral voids between the layers. It can be seen from Fig. 4 that within the BaS_3 layers the S-S distances are

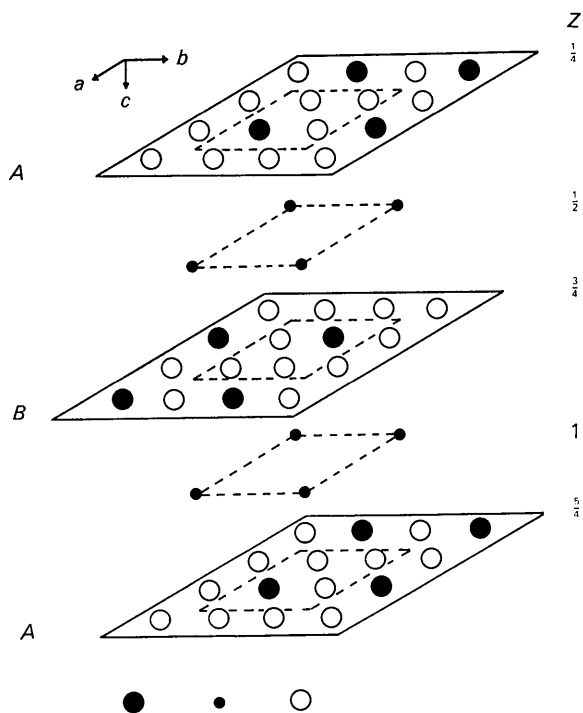


Fig. 3. Schematic diagram of close-packed layer structure of BaVS_3 . Dashed lines indicate outline of unit cell.

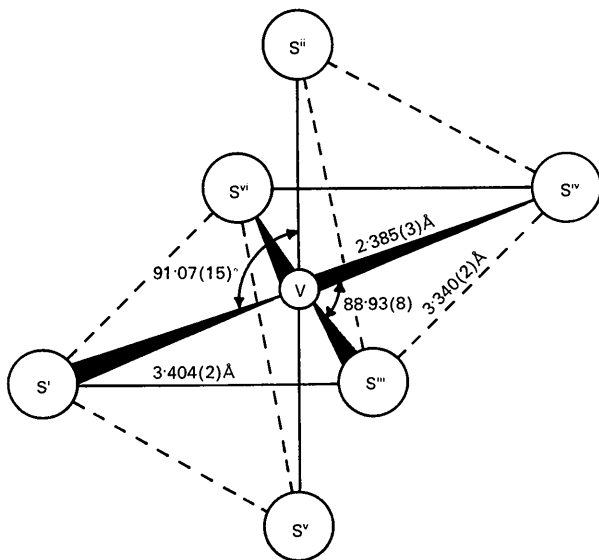


Fig. 4. Vanadium occupied sulfur octahedron with bond distances and angles. Dashed lines indicate the planes of close-packed layers. Errors are noted in parentheses and represent standard deviations.

$3.340 \pm 0.002 \text{ \AA}$ while the distance between sulfurs in adjacent layers is $3.404 \pm 0.002 \text{ \AA}$. The S-V-S angle for sulfur atoms in adjacent layers is $91.07 \pm 0.15^\circ$ and $88.93 \pm 0.08^\circ$ for sulfur atoms in the same layer. The Ba-S distance (not shown in Fig. 4) within the layers is $3.362 \pm 0.003 \text{ \AA}$. The errors on the distances and angles are standard deviations. In a perfect close-packed structure Ba-S and S-S distances should be the same. However, the Ba-S and S-S distances within the layers are shorter than the corresponding distances between adjacent layers.

An exploratory diffraction pattern was recorded at 77°K up to $2\theta = 80^\circ$. It was observed that the overall diffraction pattern at 77°K showed a considerable change when compared with the room temperature pattern. Numerous splittings and great changes in the intensities of the hexagonal lines were observed. When the sample was warmed to room temperature its X-ray pattern was identical to the original hexagonal pattern.

In order to determine the temperature at which the structure changes begin to occur X-ray diffraction patterns were recorded at several temperatures between 298°K and 77°K from $2\theta = 30^\circ$ to $2\theta = 37^\circ$. Between 2θ values of 30° to 37° , the observed splittings were most pronounced. The temperature for each X-ray scan was maintained to within $\pm 2^\circ$. A diagram of the relative intensities of the diffraction peaks vs. 2θ for $T = 298^\circ, 183^\circ, \text{ and } 77^\circ\text{K}$ is presented in Fig. 5. A crystallographic change on cooling is first noticed at approximately 183°K as determined from the first observable splitting of the 200 and 201 diffraction peaks of the hexagonal structure. The extent of the splitting of these peaks is shown in Fig. 5. It appears from these low temperature observations that the structural change is still incomplete at 77°K . The diffraction pattern at this temperature could be indexed tentatively on an orthorhombic cell with $a = 11.55$, $b = 6.52$, $c = 5.54 \text{ \AA}$. The following relationships exist between the hexagonal and orthorhombic cells: $a_0 \approx \sqrt{3} a_h$; $b_0 \approx a_h$; $c_0 \approx c_h$. Such transitions are quite common for ABX_3 type compounds.

From Fig. 1 it can be seen that there is a resistivity minimum at approximately 130°K . Above this temperature, the resistivity increases with increasing temperature, indicating metallic behavior. Below 130°K there is a sharp increase in the resistivity with decreasing temperature. Thus the crystallographic change observed below 185°K is undoubtedly associated with the significant change in the resistivity data.

The Seebeck coefficient of BaVS_3 at room temperature has the rather low value of $-54 \mu\text{V}^\circ\text{C}^{-1}$. The values of the resistivity at room temperature and 80°K were between 10^{-3} and 10^{-2} ohm-cm , whereas the resistivity measured at 5°K was 10^{10} ohm-cm . This represents a change in the resistivity of approximately twelve orders of magnitude between 80°K and 5°K .

The metallic behavior of hexagonal BaVS_3 can be explained by examination of the structure of BaVS_3 shown in Fig. 2. It can be seen that the vanadium atoms

form chains parallel to the *c* axis. Goodenough (1963) has proposed that direct interaction between transition metal atoms can occur by the overlap of *d*-orbitals, provided the two metal atoms are within a critical distance, R_c , of each other. Goodenough has formulated an expression for the critical distance, R_c , needed for direct interaction between metal atoms in an anion lattice. The expression for R_c for 3*d* transition metal oxides is:

$$R_c^{3d}(\text{oxides}) = [3.05 - 0.03(Z - Z_{Ti}) - 0.04J(J+1)] \text{ \AA},$$

where Z_{Ti} and Z are, respectively, the atomic numbers of titanium and of the transition metal cation in question, and J is the total angular momentum quantum number of the transition metal cation. For sulfides (Goodenough, 1967) the above expression requires a correction of +0.5 Å. Hence for BaVS₃ it is anticipated that R_c for V⁴⁺-V⁴⁺ interaction is approximately 3.45 Å.

In the structure of the room temperature form of BaVS₃ shown in Fig. 2, the distance between successive vanadium atoms through the faces of the shared octahedra is $\frac{1}{2}(c) = \frac{1}{2}(5.610) = 2.805$ Å. (The V-V distance in vanadium metal is 2.61 Å.) Thus the metal-metal distance along the *c* axis is clearly less than $R_c = 3.45$ Å and metallic conduction should be observed. The observed metallic behavior of hexagonal BaVS₃ is consistent with the concepts proposed by Goodenough.

The change in electrical behavior is related to a crystallographic transition in which the hexagonal structure is distorted. The exact nature of the distortion is unknown but it undoubtedly affects the V-V chains which are parallel to the *c* axis in the hexagonal structure. Any type of distortion in these chains would interfere with the delocalization of the electrons and would explain the marked increase in the resistivity of the sample below 130°K.

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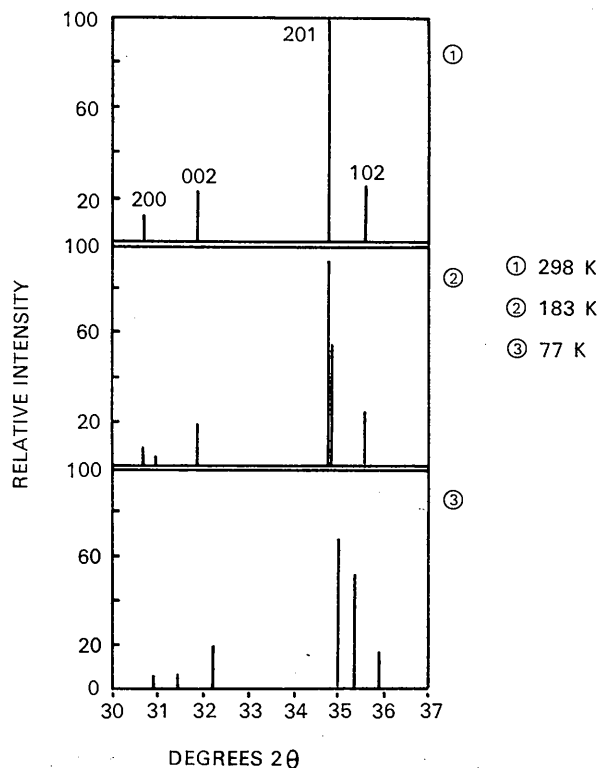


Fig. 5. Schematic diagram of relative intensities vs. 2θ for $T = 298^\circ, 183^\circ$ and 77°K .

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The Structure of Some Alkaline-Earth Metal Uranates

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The structures of CaUO_4 , SrUO_4 (orthorhombic), BaUO_4 , Ca_2UO_5 , Sr_2UO_5 , Ca_3UO_6 , and Sr_3UO_6 have been, where necessary, further determined and refined from neutron powder diffraction data. Least-squares parameters were obtained by fitting a calculated profile to the observed data. The standard deviations in the atomic positions varied with the number of independent structure parameters from 0.0007 Å for CaUO_4 to 0.029 Å for Sr_3UO_6 .

Introduction

The crystal structures of CaUO_4 (Zachariasen, 1948) and BaUO_4 (Samson & Sillén, 1947) were determined previously with the use of both single-crystal and powder X-ray techniques. SrUO_4 (orthorhombic) was found to be isomorphous with BaUO_4 (Ippolitova, Simanov, Kovba, Polunina & Bereznikova, 1959). The rhombohedral form of SrUO_4 (Zachariasen, 1948) was found to be formed only in the absence of oxygen (Ippolitova *et al.*, 1959; Cordfunke & Loopstra, 1967). This phase is probably oxygen-deficient and has therefore been excluded from the present investigation.

Ca_2UO_5 and isostructural Sr_2UO_5 were solved by X-ray powder methods, but only as regards the metal positions (Sawyer, 1963). Ca_3UO_6 and Sr_3UO_6 , which also are isostructural, were determined from X-ray and neutron diffraction powder data (Rietveld, 1966).

The present investigation was undertaken to determine the oxygen positions in Ca_2UO_5 and Sr_2UO_5 and to obtain better oxygen coordinates in the other compounds by using neutron diffraction data and the profile refinement technique (Rietveld, 1967, 1968).

Experimental

All compounds were prepared by heating stoichiometric mixtures of UO_3 and the alkaline earth metal carbonates, or nitrates, at 1000°C until X-ray powder diagrams showed the product to react no further. The final products contained only a few traces of impurities except Ca_2UO_5 where several per cent of CaUO_4 and Ca_3UO_6 were still present even after heating for weeks.

Neutron powder diagrams were obtained under the conditions listed in Table 1. The impurity lines in the diagram of Ca_2UO_5 were corrected for by subtracting properly scaled diagrams of CaUO_4 and Ca_3UO_6 obtained under identical conditions.

Table 1. *Experimental details*

α_1 is the angular divergence of the collimator between the reactor and the monochromator, α_3 that of the collimator in front of the BF₃ detector; λ is the wavelength used and $(\sin \theta_m)/\lambda$ the range of observation.

Compound	α_1	α_3	λ	$(\sin \theta_m)/\lambda$
CaUO_4	30'	30'	2.576 Å	0.350
SrUO_4	10	10	2.566	0.350
BaUO_4	10	10	2.562	0.350
Ca_2UO_5	10	10	2.565	0.348
Sr_2UO_5	10	10	2.565	0.333
Ca_3UO_6	10	10	2.565	0.353
Sr_3UO_6	5.5	10	1.103	0.373

X-ray powder intensities were collected on a Philips diffractometer with Cu $K\alpha$ radiation. Unit-cell data for all compounds are shown in Table 2.

Structure determination of Sr_2UO_5 and Ca_2UO_5

From the previous X-ray work (Sawyer, 1963), the metal atoms in Sr_2UO_5 had been found to occupy the positions given in Table 3. Packing considerations led to initial parameters of the oxygen atoms. These were used to construct four structure models which differed from each other only with regard to the sign of the Sr y parameters. The Sr coordinates of all four models were then refined by a least-squares method (Rietveld,